



Dynamic Characteristics

C_{iss}	Input Capacitance	Q1: $V_{DS} = 13 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	Q1		1590	2230	pF
			Q2		5070	7100	
C_{oss}	Output Capacitance	Q2: $V_{DS} = 13 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	Q1		411	575	pF
			Q2		1290	1810	
C_{rss}	Reverse Transfer Capacitance		Q1		71	100	pF
			Q2		162	230	
R_g	Gate Resistance		Q1	0.1	0.5	1.0	Ω
			Q2	0.1	0.4	1.0	